

# isc Silicon NPN Power Transistor

### **DESCRIPTION**

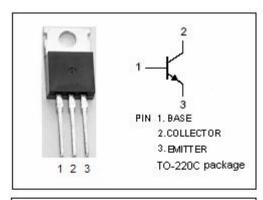
- · High Breakdown Voltage-
  - : V<sub>(BR)CBO</sub>= 800V(Min)
- · High Switching Speed
- · Low Collector Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

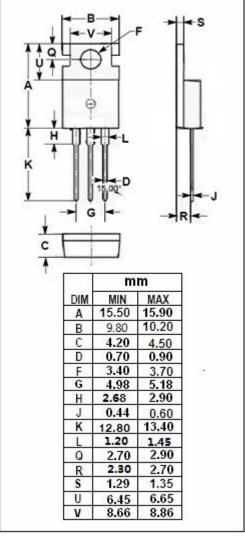


· Designed for high speed switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	800	V
Vceo	Collector-Emitter Voltage	500	V
V <sub>EBO</sub>	Emitter-Base Voltage	8	V
lc	Collector Current-Continuous	5	А
Ісм	Collector Current-Peak	10	А
l <sub>Β</sub>	Base Current-Continuous	3	Α
Pc	Collector Power Dissipation @ $T_C$ =25 $^{\circ}$ C	40	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$







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2SC2832

#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 30mA; ; I <sub>B</sub> = 0	500			V		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			1.0	V		
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			1.5	V		
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 800V; I <sub>E</sub> = 0			0.1	mA		
ІЕВО	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			0.1	mA		
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 5V	15					
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A; V <sub>CE</sub> = 5V	8					
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 10V		3		MHz		
Switching times								
t <sub>on</sub>	Turn-on Time				1.0	μ \$		
t <sub>stg</sub>	Storage Time	I <sub>C</sub> = 3A, I <sub>B1</sub> = -I <sub>B2</sub> = 0.6A; V <sub>CC</sub> = 200V			3.0	μ \$		
t <sub>f</sub>	Fall Time				1.0	μ \$		

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